

Electronic Supplementary Information
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**Solvent-assisted preparation of low-temperature SnO₂
electron transport layers for efficient and stable perovskite
solar cells made in ambient conditions**

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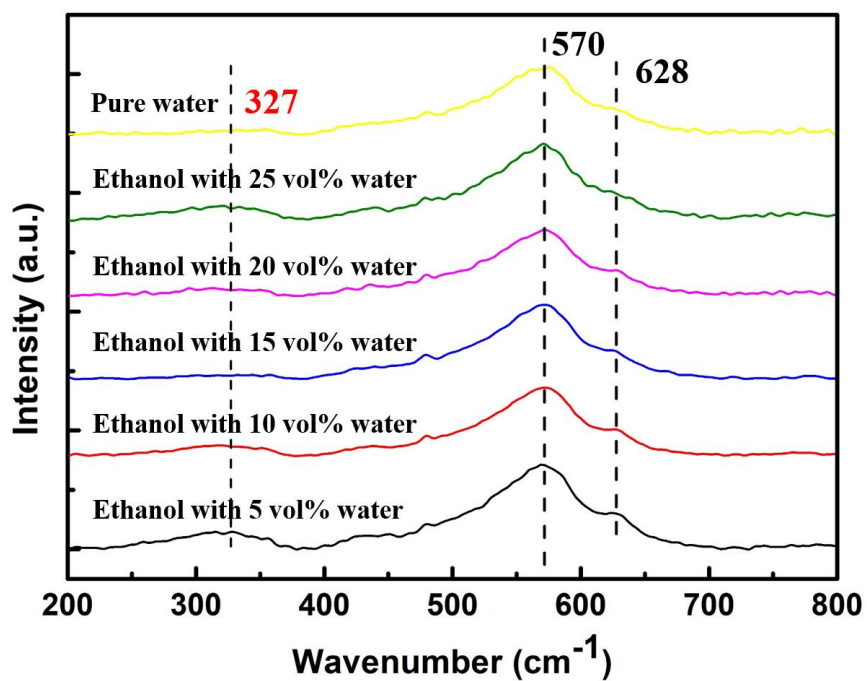


Fig. S1. Raman spectra of SnO₂ nanocrystals which prepared using different solutions.

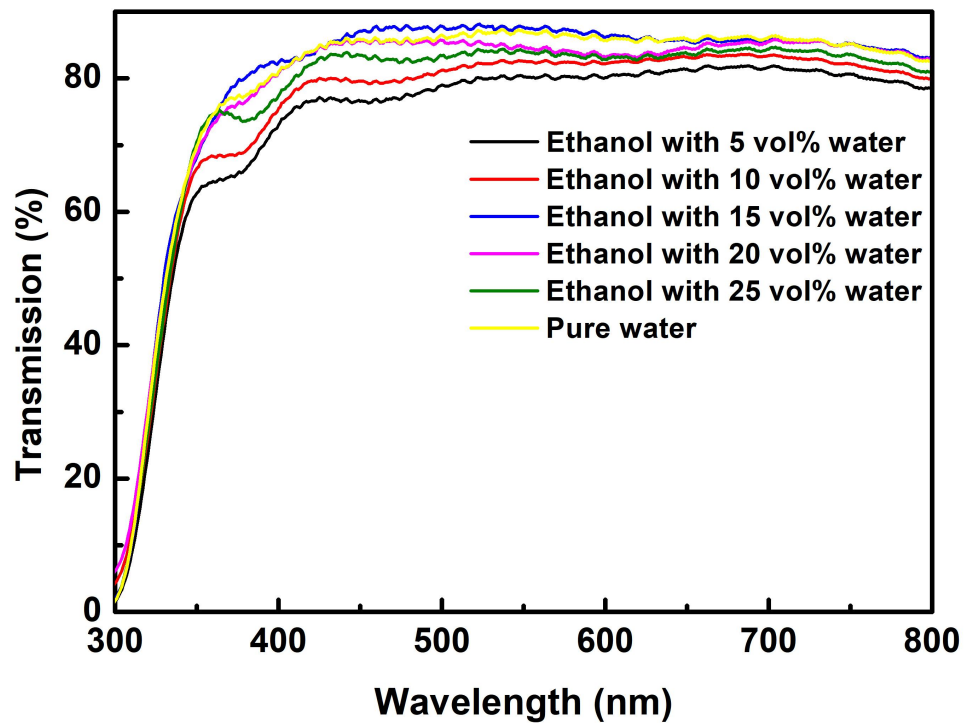


Fig. S2. UV-visible spectra of FTO/SnO₂ prepared using different solutions.

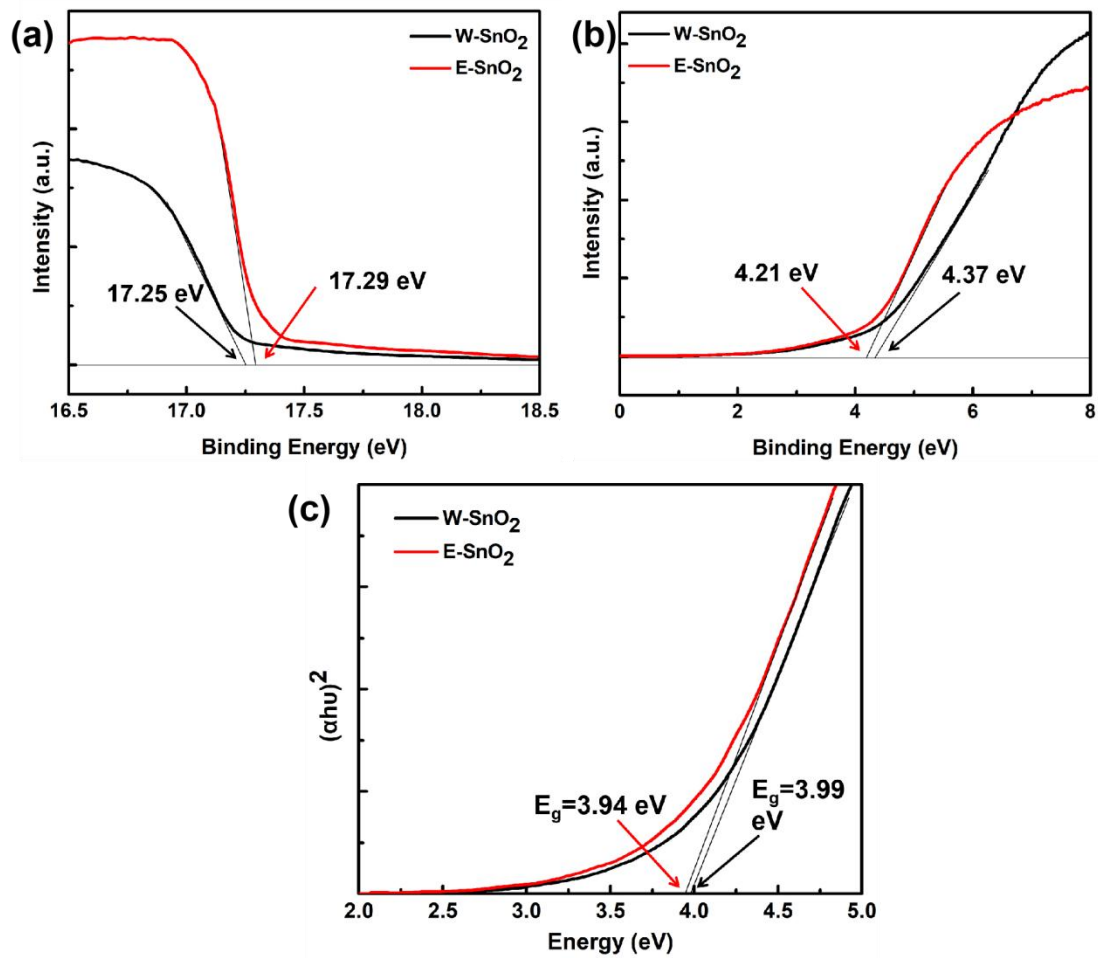


Fig. S3. (a), (b)UPS spectra describing the cut-off energy and onset energy boundaries for W-SnO₂ and E-SnO₂. (c) The band gaps of W-SnO₂ and E-SnO₂.

The average decay time (τ_{ave}) is calculated by Eq. (S.1) [1]

$$\tau_{ave} = \sum_{i=1}^n A_i \tau_i \quad (\text{S.1})$$

Here, τ_{ave} is average decay time, A_i is the decay amplitude, and τ_i is the decay time.

The hysteresis index (HI) is calculated by Eq. (S.2)

$$HI = \frac{PCE_{\text{reverse}} - PCE_{\text{forward}}}{PCE_{\text{reverse}}} \quad (\text{S.2})$$

The trap-state density (n_{trap}) is calculated by the the Eq. (S.3) [2]

$$n_{\text{trap}} = \frac{2\varepsilon\varepsilon_0V_{\text{TFL}}}{eL^2} \quad (\text{S.3})$$

Where ε_0 is the vacuum permittivity ($\varepsilon_0=8.85\times 10^{-12}$ F/m), ε is the relative dielectric constant of the perovskite ($\varepsilon_{\text{perovskite}}\approx 35$), e is the elemental charge ($e=1.6\times 10^{-19}$ C), and L is the thickness of the measured perovskite film.

Table S1. ZView2 fitting parameters obtained from the EIS data of the champion E-SnO₂-PSC and W-SnO₂-PSC.

Device	R_s	R_{rec}	C
E-SnO ₂ -PSC	49.38	1816.04	7.831E ⁻⁹
W-SnO ₂ -PSC	68.41	952.32	5.081E ⁻⁹

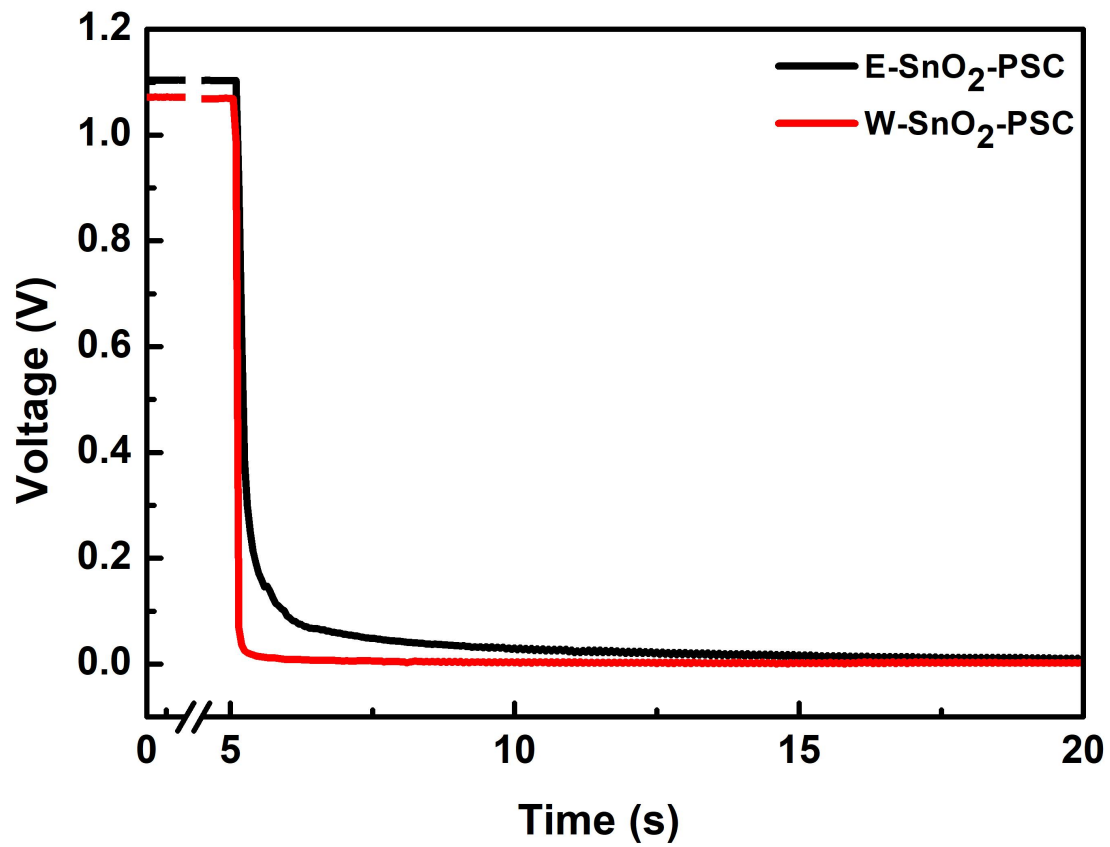


Fig. S4. OCVD curves for E-SnO₂-PSC and W-SnO₂-PSC.

References:

- [1] B. Wu, K. Fu, N. Yantara, G. Xing, S. Sun, T. Sum, N. Mathews, *Adv. Energy Mater.* 5 (2015) 1500829.
- [2] Q. Dong, Y. Fang, Y. Shao, P. Mulligan, J. Qiu, L. Cao, J. Huang, *Science* 347 (2015) 967-970.